

NP89N055PUK MOS FIELD EFFECT TRANSISTOR

The NP89N055PUK is N-channel MOS Field Effect Transistor designed for high current switching applications.

Features

- Super low on-state resistance $R_{DS(on)} = 4.0 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 45 \text{ A})$
- Low C_{iss} : $C_{iss} = 4000 \text{ pF TYP}$. $(V_{DS} = 25 \text{ V})$
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Pac	Package	
NP89N055PUK-E1-AY *1	Pure Sn (Tin)	Tape 800 p/reel	Taping (E1 type)	TO-263 (MP-25ZP)
NP89N055PUK-E2-AY *1			Taping (E2 type)	

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V _{GS} = 0 V)	Vdss	55	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) ($T_c = 25^{\circ}C$)	ID(DC)	±90	A
Drain Current (pulse) * ^{1, 3}	I _{D(pulse)}	±360	A
Total Power Dissipation ($T_c = 25^{\circ}C$)	P _{T1}	147	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.8	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	–55 to 175	°C
Repetitive Avalanche Current *2, 3	lar	33	A
Repetitive Avalanche Energy * ^{2, 3}	E _{AR}	108	mJ

Thermal Resistance

Channel to Case Thermal Resistance	R _{th(ch-C)*3}	1.02	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *3	83.3	°C/W

Notes: *1 T_C = 25°C, P_W \leq 10 μ s, Duty Cycle \leq 1%

*2 R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

*3 Not subject of production test. Verified by design/characterization.

Rev.2.00 May 24, 2018

R07DS0569EJ0200

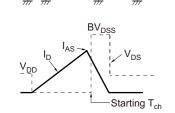


Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 55 V, V _{GS} = 0 V	
Gate Leakage Current	I _{GSS}	—	—	±100	nA	V_{GS} = ±20 V, V_{DS} = 0 V	
Gate to Source Threshold Voltage	V _{GS(th)}	2.0	3.0	4.0	V	V _{DS} = V _{GS} , I _D = 250 μA	
Forward Transfer Admittance *1	y _{fs}	30	60		S	V _{DS} = 5 V, I _D = 45 A	
Drain to Source On-state Resistance *1	R _{DS(on)}		3.3	4.0	mΩ	V _{GS} = 10 V, I _D = 45 A	
Input Capacitance *2	Ciss		4000	6000	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss		410	620	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	Crss	_	150	270	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}	_	25	60	ns	V _{DD} = 28 V, I _D = 45 A	
Rise Time *2	tr	_	10	30	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}	_	65	130	ns	R _G = 0 Ω	
Fall Time *2	t _f	_	6	20	ns		
Total Gate Charge *2	Q _G	_	68	102	nC	V _{DD} = 44 V	
Gate to Source Charge	Q _{GS}	_	18	_	nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}	_	18		nC	I _D = 90 A	
Body Diode Forward Voltage *1	V _{F(S-D)}	_	0.9	1.5	V	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Time	trr	_	47		ns	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr	_	80		nC	di/dt = 100 A/µs	

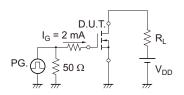
Note: *1 Pulsed test

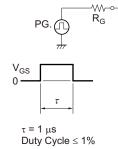
Note: *2 Not subject of production test. Verified by design/characterization.

TEST CIRCUIT 1 AVALANCHE CAPABILITY



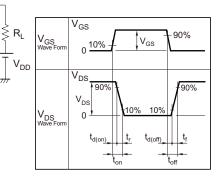
TEST CIRCUIT 3 GATE CHARGE





TEST CIRCUIT 2 SWITCHING TIME

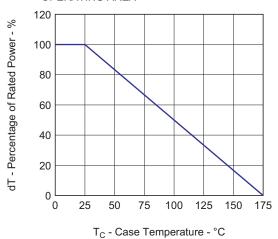
D.U.T.

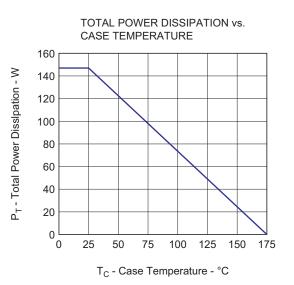




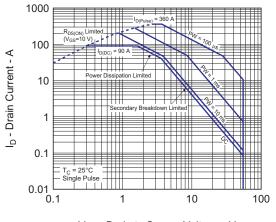
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



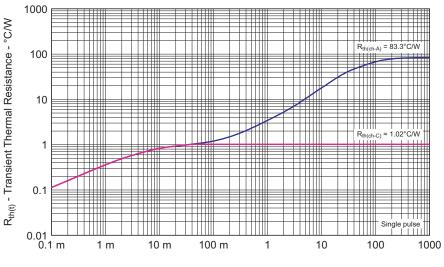


FORWARD BIAS SAFE OPERATING AREA



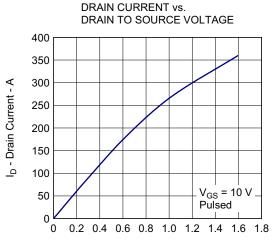


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

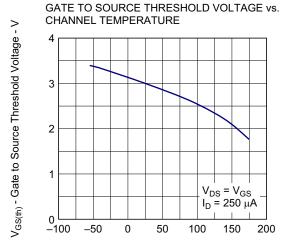


PW - Pulse Width - s

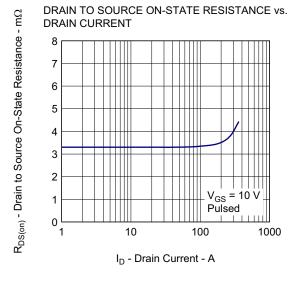




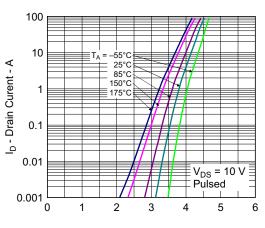
V_{DS} - Drain to Source Voltage - V



T_{ch} - Channel Temperature - °C

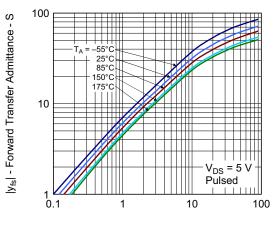


FORWARD TRANSFER CHARACTERISTICS



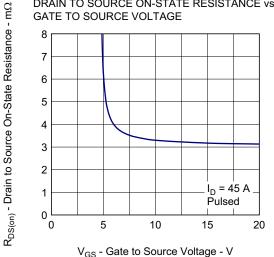
V_{GS} - Gate to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



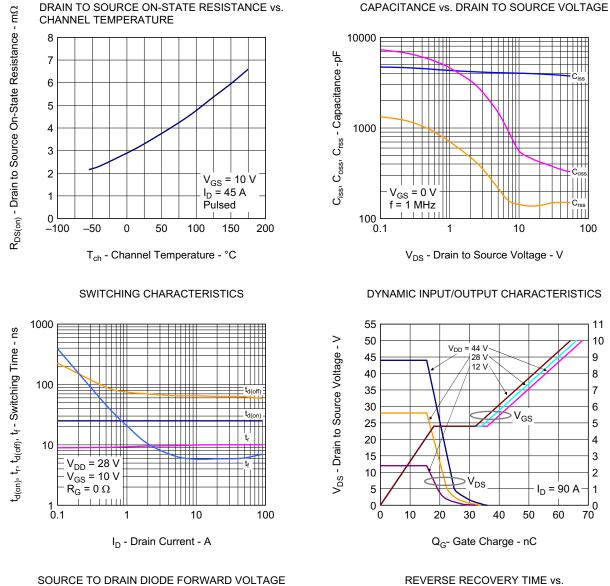
I_D - Drain Current - A

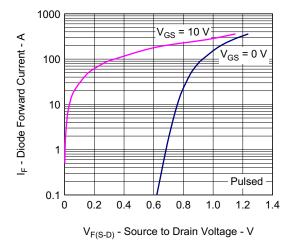
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



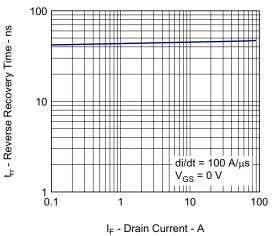


NP89N055PUK





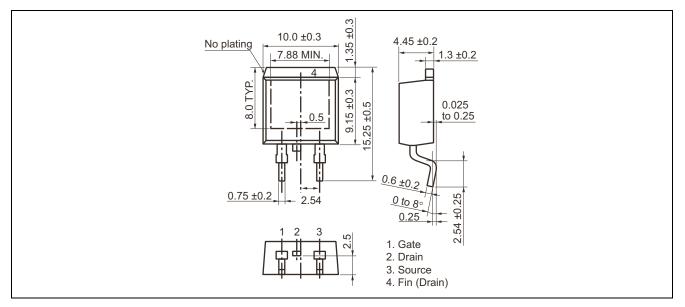
DRAIN CURRENT



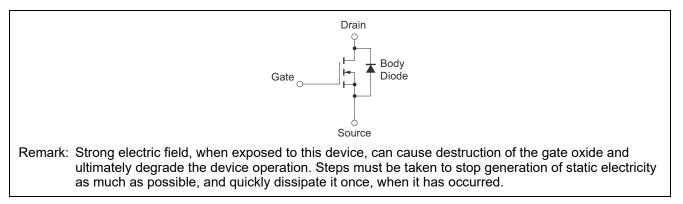
V_{GS} - Gate to Source Voltage - V

Package Drawing (Unit: mm)

TO-263 (MP-25ZP) (Mass: 1.5 g TYP.)



Equivalent Circuit





NP89N055PUK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Nov 17, 2011	—	First Edition Issued	
2.00	May 24 ,2018	1	Note 3 was added	
		2	Note 2 was added	

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